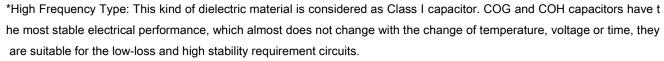


General series of ceramic chip capacitors

Feature

- *There is high reliability on monolithic structure of laminated layers.
- *And its character of excellent soldering ability and soldering resistance ability is suitable for reflow soldering and peak soldering.
- *It includes high and stable capacitance.



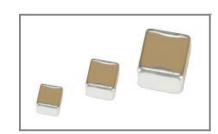
*X7R、X5R、X7S、X6S: X7R、X5R、 X7S、X6S material is a kind of material has high dielectric constant. The capacitor made of this kind material is considered as Class II capacitor whose capacitance is higher than that of class I. These capacitors are classified as having a semi-stable temperature characteristic and used over a wide temperature range, such in these kinds of circuits, DC-blocking, decoupling, bypassing, frequency discriminating etc.

执行标准: GB/T 21041-2007 GB/T 21042-2007

Executive Standard: GB/T 21041-2007 GB/T 21042-2007

Application

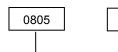
*It is suitable for all kinds of filter, coupled, harmonic vibration, bypassing and high frequency circuits.



Ν



♦ How To Order



Size Code Size (L×W) (L×W) Code inch mm 0.01×0.005 0.40×0.20 1005 0201 0.02×0.01 0.60×0.30 0402 0.04×0.02 1.00×0.50 0603 0.06×0.03 1.60×0.80 0.08×0.05 0805 2.00×1.25 1206 0.12×0.06 3.20×1.60 0.12×0.10 3.20×2.50 1210 1808 0.18×0.08 4.50×2.00

0.18×0.12

1812

4.50×3.20

CG 102

 NominI Capacitance

 Express Method
 Actual Value

 0R5
 0.5

 1R0
 1.0

 102
 10×10²

Note: the first two digits are significant; third digit denotes number of zeros; R=decimal point. Rated Voltage
unit: V

Express
Method Actual Value

6R3 6.3

 50×10^{0}

 20×10^{1}

500

Note: the first two digitsare significant; third digit denotes number of zeros; R=decimal point.

500

201

Packag	e Styles
Express Method	Package Styles
В	Bulk Bag
Т	Taping Package

Dielectric Code										
Dielectric Code	Dielectric									
CG	C0G									
Х	X5R									
В	X7R									
BS	X7S									
BT	X7T									
DS	X6S									
DT	X6T									

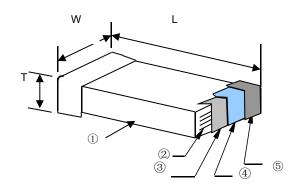
	Capacitance 1	Tolerance
Code	Tolerance	Note
Α	±0.05pF	These
В	±0.10pF	Capacitance
С	±0.25pF	tolerance A,
D	±0.50pF	B, C, D are just
F	±1%	applicable the
G	±2%	capacitance that
J	±5%	equals to or less
K	±10%	than 10pF。
М	±20%	
S	-20% +50%	
Z	-20% +80%	

J

Terminal Material Styles									
Termination Styles	Express Method								
Copper Solderable Termination	С								
Nickel Barrier Termination	N								

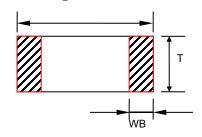
Product Structure

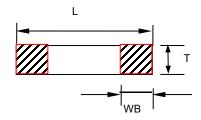
NO	Name
1	Ceramic dielectric
2	Inner electrode
3	Substrate electrode
4	Nickel Layer
5	Tin Layer





♦ Product Dimensi L





Т	уре		Dimensio	ns (mm)		
British expression	Metric expression	L	W	Т	WB	Special Instructions
1005	0402	0.4±0.02	0.2±0.02	0.2±0.02	0.1±0.03	All
0201	0603	0.6±0.03	0.3±0.03	0.3±0.03	0.15±0.05	C<220nF
0201	0603	0.6±0.05	0.3±0.05	0.3±0.05	0.15±0.05	C≥220nF
		1.00±0.05	0.50±0.05	0.50±0.05	0.25±0.05	C<1uF
0402	1005	1.00±0.15	0.50±0.15	0.50±0.15	0.25±0.05	1uF≤C<10uF
		1.00±0.20	0.50±0.20	0.50±0.20	0.25±0.05	C≥10uF
0603	1608	1.60±0.10	0.80±0.10	0.80±0.10	0.35±0.20	C≤1uF
0603		1.60±0.20	0.80±0.20	0.80±0.20	0.35±0.20	C>1uF
2005		2.00±0.20	1.25±0.20	0.80±0.20	0.50±0.20	C<0.47µF
0805	2012	2.00±0.20	1.25±0.20	1.25±0.20	0.50±0.20	C≥0.47µF
		3.20±0.30	1.60±0.30	0.80±0.20	0.60±0.30	C≤220nF
1206	3216	3.20±0.30	1.60±0.30	1.00±0.20	0.60±0.30	220nF <c<1µf< td=""></c<1µf<>
		3.20±0.30	1.60±0.30	1.60±0.30	0.60±0.30	C≥1µF
1210	3225	3.20±0.30	2.50±0.30	≤2.80	0.60±0.30	All
1808	4520	4.50±0.40	2.00±0.20	≤2.20	0.60±0.30	All
1812	4532	4.50±0.40	3.20±0.30	≤3.50	0.60±0.30	All

Note: 1. The specific thickness of the product can read "capacity range and voltage "in this approval sheet

2. We can design according to customer special requirements

◆Temperature Coefficient /Characteristics

V. Isanipolatano di Santano di Sa											
Dielectric	Reference Temperature Point	Temperature Coefficient	Operation Temperature Range								
COG	20°C	0±30 ppm/℃	-55℃ ~ 125℃								
X7R	20°C	±15%	-55℃ ~ 125℃								
X7S	20°C	±22%	-55℃ ~ 125℃								
X7T	20°C	-33%~+22%	-55℃ ~ 125℃								
X6S	20°C	±22%	-55℃ ~ 105℃								
X6T	20°C	-33%~+22%	-55℃ ~ 105℃								
X5R	20°C	±15%	-55℃ ~ 85℃								

Note :Nominal temperature coefficient and allowed tolerance of class $\, {\rm I} \,$ are decided by the changing of the capacitance between 20°C and 85°C. Nominal temperature coefficient of class $\, {\rm II} \,$ are decided by the temperature of 20°C.



◆Capacitance Range and Operating Voltage

*A list of the specific voltage-specific capacitors of Class I capacitors

Dielectric						C)G			
		10	05		02	01	040	2	06	03
Dimension					(0.6mm	*0.3mm)	(1.0mm*0).5mm)	(1.6mm ³	*0.8mm)
Capacity/					05) (50)/			05) (50) (
Voltage	10V	16V	25V	50V	25V	50V	25V	50V	25V	50V
0.1pF										
0.2pF										
0.5pF										
1pF										
1.2pF										
1.5pF										
1.8pF										
2.0pF										
2.2pF										
2.7pF										
3.0pF										
3.3pF										
3.6pF										
3.9pF										
4.7pF										
5.0pF						0.3±0.03				
5.6pF		0.2±	:0.02							
6.8pF										
8.0pF										
8.2pF								0.50±		
10pF					0.3±0.03		0.50±0.05	0.05	0.80±0.10	0.80±0.10
12pF										
15pF										
18pF										
22pF										
27pF										
33pF										
39pF										
47pF										
56pF										
68pF										
100pF										
120pF										
150pF										
180pF										
220pF										
270pF										
330pF										
390pF										
470pF										
560pF										



	INUTUA			
680pF				
1nF				
1.5nF				
1.8nF				
2.2nF				
2.7nF				
3.3nF				
4.7nF				
10nF				

Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requirements

Dielectric				C	:0G				
Dimension	0805		1:	1206		10	1812		
Dimension	(2.0mm*	1.25mm)	(3.2mm	n*1.6mm)	(3.2mm ³	[*] 2.5mm)	(4.5mm*3.2mm)		
Capacity/	25V 50V		25V	50V	25V	50V	25V	50V	
Voltage			250	30 0	250	30 V	250	30 V	
0.1pF									
0.22pF									
0.3pF									
0.47pF									
1pF									
1.2pF									
1.5pF									
1.8pF									
2.0pF									
2.2pF									
2.7pF									
3.0pF									
3.3pF									
3.6pF									
3.9pF									
4.7pF									
5.0pF	0.8±	0.02	0.8:	±0.02					
5.6pF									
6.8pF									
8.0pF									
8.2pF									
10pF									
12pF									
15pF									
18pF									
22pF									
27pF					4.05	10.00	4.0	0.00	
33pF					1.25	£0.20	1.6±0	0.30	
39pF									
47pF									
56pF									
68pF									
100pF									



- FEINE	THUA -			
120pF				
150pF				
180pF				
220pF				
270pF				
330pF				
390pF				
470pF				
560pF				
680pF				
1nF				
1.5nF				
1.8nF				
2.2nF				
2.7nF				
3.3nF				
4.7nF				
6.8nF				
10nF		1.25±0.20		
12nF	1.25±0.20			
22nF	1.2010.20			
33nF		1.60±0.30	 	
47nF				
100nF			 	

Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requirement。

^{*}A list of the specific voltage-specific capacitors of Class I capacitors

Dimension		1005 (0.4mm*0.2mm)													
Dielectric		X7R 系	列	X7S 系列 X7T 系列					X6	S/X6T ≸		X5R 系列			
Capacity/ Voltage	6.3V	10V	16V	6.3V	10V	16V	6.3V	10V	16V	6.3V	10V	16V	6.3V	10V	16V
120pF															
180pF															
220pF															
270pF															
330pF		0.2±0.0	าว												
390pF		U.ZIU.(JZ												
470pF					0.2±0.02										
560pF)	0.2±0.02			0.2±0.02		
680pF					U.ZIU.UZ	4		U.ZIU.UZ	4		U.ZIU.U2	2		U.ZIU.UZ	4
1nF															
1.2nF															
1.5nF															
1.8nF															
2.2nF															
2.7nF															
3.3nF															



	NOH	UA					
3.9nF							
4.7nF							
5.6nF							
6.8nF							
10nF							
15nF							

Dimension												(0.6m	0201 m*0.	3mm))										
Dielectric		X7	'R系	列			X	7S系	列			X	/T系	列			X6S	/X6T	系列			X	5R系	列	
Capacity/ Voltage	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V
120pF																									
180pF																									
220pF		0.3±0.03																							
330pF			0.3±	0.03			0.	3±0.0)3			0.	3±0.0)3			0.	3±0.0							
470pF																									
560pF																									
680pF																									
1nF																									
2.2nF			0.3±	.n na			0	3±0.0	12			0	3±0.0	12			0	3±0.0	0 2						
3.9nF			U.3±	.0.03			0.	3±0.0)3			0.	3±0.0	13			U.	.S±U.(03						
4.7nF																									0.30
5.6nF		0	3±0.0	าว			0.3±	0 02																	0.30
6.8nF		0.	3±0.0	JS			U.3I	0.03																	0.03
10nF												0.3±	0.02				0.21	:0.03							0.03
15nF												0.3±	0.03				U.3±	0.03							
18nF		0.3±	0.03			0.	3±0.0)3														0.20	. 0 00		
22nF																						0.30	£0.03		
33nF																									

Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requirement

Dimension											((0.6m	0201 m*0.)										
Dielectric		X	'R 系	列			X	7S 系	列			X	7T系	列			X6S	/X6T	系列			X	R 系	列	
Capacity/ Voltage	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V
47nF																									
56nF						0.3±	:0.03					0.3±	0.03			0.3±0.05						0 20 1	0.05		
68nF																0.3±0.05						0.30±	:0.05	1	
100nF																									
220nF						0.3±	0.05																		
330nF											0.7					0.3	80±				0.0				
470nF											0.3					0.0	05				0.3				
1µF											0.0	UO									0.0	ບວ			
2.2µF																									

Dimension	0402
Dimension	(1.0mm*0.5mm)

$\mathbb{Z}^{\mathbb{R}}$	风华高科
	FENGHUA

	FI	ENG	JHL	AL																					=
Dielectric		X7	R 系	列			X7	7S 系	列			X7	7T 系	列			X6S	3/X6T	系列			X5	R系	列	
Capacity/	6.3V	10\/	16\/	25\/	50\/	6 31/	10\/	16\/	25\/	50\/	6 31/	10\/	16\/	25\/	50\/	6 31/	10\/	16\	/ 25\/	50\/	6 3//	10\/	16\/	25\/	50\/
Voltage	0.5	100	100	250	30 V	0.5 v	10 V	10 0	230	30 V	0.5 V	10 0	100	230	30 V	0.5 V	100	100	250	30 V	0.5 v	100	100	23 V	30 V
330pF																									
470pF																									
560pF																									
680pF																									
1nF																									
2.2nF																									
3.9nF																									
4.7nF		0.50±0.05																							
5.6nF							0.5	50±0.0	05			0.5	50±0.	05			٥	.50±0	0.05						
6.8nF							0.0)U±U.	03			0.0)U±0.	03			U.	.50±(7.03						
10nF																									
15nF																									
18nF																									
22nF																									
33nF																									
47nF																									0.50
56nF																									±
68nF																					Ш				0.05
100nF					1																	0.50±	£0.05		
220nF	С).50±	0.05				0.50±	£0.05																	
330nF	0.50	0±0.0	15			0.5	50±0.	05				n 504	±0.05) <u>5</u> 0	±0.0	5			0.50±	LO 05		
470nF	0.5	0±0.0	,5									0.501	20.03				J.50	±0.0	J			0.502	20.03		
680nF	0.50					0.5	60± 05																		
1μF	0.50 0.1					0.5	i0± 15																		
						0.50 ±						0.50±	±0.15				0.50	±0.1	5			0.50±	±0.15		
2.2µF						0.15																			
4.7µF											0.5	0±0.	15			0.5	0±0	.15			0.5	50±0.	15		
											0.5	0 Τ				0.5	٦								
6.8µF											0.5 0.1					0.5					0.5	0±			
											U.	13				0.	J				0.	15			
10µF											0.5					0.5					0.5				
. σμι											0.2	20				0.2	20				0.2	20			

Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requirement

Dimension													0603												
Dimension												(1.6m	ım*0.	8mm)										
Dielectric		X	X7R 系列 X7S 系列 X7T 系列 X6S/X6T 系列 X5R 系列																						
Capacity/	6.3V	10\/	16\/	25\/	50\/	6.3V	10\/	16\/	25\/	50\/	6 21/	10\/	16\/	25\/	50\/	6 21/	10\/	16\/	25\/	50\/	6 21/	10\/	16\/	25\/	50\/
Voltage	0.31	100	100	250	50 v	0.31	10 V	100	250	30 V	0.31	10 V	100	250	300	0.31	100	100	250	300	0.3	100	100	250	30 V
330pF																									
470pF		0.8±0.1 0.8±0.1 0.8±0.1																							

	FEN	<u> </u>	LΙΑ	_											_
560pF															
680pF															
1nF															
2.2nF															
3.9nF															
4.7nF															
5.6nF															
6.8nF											Ш				
10nF											Ш				
15nF															
18nF															
22nF															
33nF															
47nF											Ш				
56nF											Ш				
68nF											Ш				
100nF															
220nF															
330nF											ш				
470nF												0.	8±0.′	1	
680nF															
1µF	0.0			Γ		0.00		0.010.0	0.0.0				0.0		
2.2 µF	0.8	±0.2			0	.8±0.2		0.8±0.2	0.8±0	.2		0.	8±0.2	2	
3.3 µF	0.8±0.2				0.8±	0.2		_	0.010.0	-	_		0.0	-	
4.7 µF							+	0.8±0.2	0.8±0.2			0.8±	0.2	-	\dashv
6.8 μF 10 μF							+		-						\dashv
							+								$\overline{}$
15 μF 22 μF							+	0.8±0.2	0.8±0.2		0.8±0).2	\dashv		\dashv
ΖΖ μΓ							+	0.8±	0.8±		0.8±				\dashv
47μF								0.2	0.2		0.2				

《工® 风华高科

Dimension										(2		0805 m*1.2	25mm	1)										
Dielectric		X7R 3	系列			X7	7S 系	列			X	7T系	列			X6S	/X6T	系列			X	SR系	列	
Capacity/ Voltage	6.3V	10V 16	/ 25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3\	/ 10V	16V	25V	50V	6.3V	10V	16V	25V	50V
330pF																								
470pF																								
560pF																								
680pF																								
1nF																								
2.2nF		0.8±0	າ			0	.8±0.	2			0	.8±0.	2			0	.8±0.	2						
3.9nF		0.01	J. Z			U	.010.	_			U	.O±0.	_			U	.010.	_						
4.7nF																								
5.6nF																								
6.8nF																								
10nF																								
15nF																								



Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requiremen

Dimension											,,		0805												
				-							(2			25mm	1)				~ =1		1			-	
Dielectric		X	7R系	列				X7S				X7	/T 系	列			X6S	X6T	系列			X5	R系	列	
Capacity/	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V
Voltage																									
18nF																									
22nF																									
33nF																0.8±0.2									
47nF																0.8±0.2									
56nF		0	.8±0.	2			0	.8±0.	2			0	.8±0.	2		0.8±0.2									
68nF																0.8±0.2									
100nF																0.010.2									
220nF																									
330nF																									
470nF																									
680nF		1	25±0	2			1	25±0	2																
1µF			2010					2010				1	25±0	2			1.	25±0	.2			1.	25±0	.2	
2.2µF												١.	20±0	.2											
3.3µF		1 25	±0.2				1.25	+0.2																	
4.7µF		1.20	10.2				1.20	10.2																	
6.8µF	4 '	25±0	2			1	.25±0	2																	
10μF	1.4	23±0	.2			1.	.23±0	.2																	
15µF												1 25	TU 3									1.25	±0.2		
22µF												1.25	±0.2				1.25	±0.2							
47µF											1.25	±0.2				1.25 ±0.2					1.25	±0.2			

Dimension													1206												
Dielectric		X7	'R 系	列			X7	7S 系	列			(3.2m X7	IIII 1. 7T系		,		X6S	/X6T	系列			X.F	FR系	列	
Canacity/	6.3V				50V	6.3V				50V	6.3V				50V	6.3V				50V	6.3V				50V
330pF																									
470pF																									
560pF																									
680pF																									
1nF																									
2.2nF																									
3.9nF																									
4.7nF		0	.8±0.	2			٥	.8±0.	2			0	.8±0.	2			0	.8±0.	2						
5.6nF		U	.010.				U	.O±0.	_			U	.010.	_			U	.O <u>±</u> 0.							
6.8nF																									
10nF																									
15nF																									
18nF																									
22nF																									
33nF																									
47nF																									

	® 风华高科 FENGHUA -			GEN	NERAL MLCC
56nF					
68nF					
100nF					
220nF					
330nF					
470nF	1.25±0.2	1.25±0.2	1.25±0.2	1.25±0.2	
680nF					
1µF	16103	16103	16103	16103	16103
2 2uF	1.6±0.3	1.6±0.3	1.6±0.3	1.6±0.3	1.6±0.3

Note: 1, C	Jones	spond	aing p	produ	ct de	sign t	nickn	iess ,	unit:	mm ∠	z, vve c	an des	sign ac	corai	ing to c	custo	mer	speci	ai red	quiren	nent			
Dimension												120	16											
Dimension											(3.2	2mm*	1.6mm	1)										
Dielectric		X	7R系	列			X	7S 系	列			X7T 🤋	系列			X6S/	X6T	系列			Χŧ	5R系	列	
Capacity/	0.01/	40) (40) (05) (50) (0.01/	40) (40) (05) (50) (0.00/40	. / . 0	, 05)	50) /	0.01/	40) (40) (05) (50) (2 0) (40) (40) (05) (50) (
Voltage	6.3V	10V	160	250	500	6.30	100	160	250	500	6.3V 10	V 16	V 25V	500	6.30	100	16V	25V	500	6.30	10V	160	250	500
3.3µF			•	•					•															
4.7µF			0.0	•				0.0	_			4.0.					0.0	_				0.0	•	
6.8µF		1	.6±0.	.3			1	.6±0.	.3			1.6±	0.3			1.	.6±0.	3			1	.6±0.	.3	
10μF																								
15µF	4.0.	0.0					2.0	_			,	0.00				4.0.					4.0			
22µF	1.6±	1.6±0.3					1	6±0.3	•			1.6±	:0.3				1.6:	±0.3						
47µF						4.01					1.6±	0.3			1.	6±0.:	3			1	.6±0.	3		
100 5			1.6±								4.0.0				4.0.	0.0				1.6±				
100µF						0.3					1.6±0.	3			1.6±	0.3				0.3				



Dimension												(3.2m	1210 m*2.		1)										
Dielectric		X7	7R系	列			X7	S 系	列				/T 系				X6S	X6T	系列			X	5R 系	.列	
Capacity/																				l					
Voltage	6.3V	10V	16V	25	50V	6.3V	100	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	160	250	50V	6.3V	10V	16V	250	500
330pF					•																				
470pF																									
560pF																									
680pF																									
1nF																									
2.2nF																									
3.9nF																									
4.7nF																									
5.6nF																									
6.8nF		1.	25±0).2			1.:	25±0	.2			1.	25±0	.2			1	.25±0	0.2						
10nF																									
15nF																									
18nF																									
22nF																									
33nF																									
47nF																									
56nF																									
68nF																									
100nF																									
220nF		1	.4±0.	.2			1.	4±0.	.2			1	.4±0.	2			1	1.4±0	.2						
330nF																									
470nF							1.	.6±0.	3			1	.6±0.	3			1	1.6±0	0.3						
680nF																									
1μF	-	1	.6±0.	.3																					
2.2µF	-						2	.5±0.	3			2	.5±0.	3			2	2.5±0	0.3						
3.3µF												Ť													
4.7µF																					2	2.5±0.	3	1.8	±0.3
6.8µF																									
10μF												2.5±	0.3				2.5	±0.3		_					
15µF	2.5:	±0.3				2.5±	0.3													_		2.5	£0.3		
22µF	-																								
47μF												.5±0.	3			2	.5±0	.3		_		2.5±0.			
100μF											2.5:	±0.3									2.5±	0.30			

Note: 1、Corresponding product design thickness, unit:mm 2、We can design according to customer special requirement

D:													1808												
Dimension												(4.5m	nm*2.	0mm)										
Dielectric		X	7R 系	列			X	7S 系	列			X	7T 系	列			X6S	/X6T	系列			Χŧ	5R 系	列	
Capacity/	6.3V	10\/	16)/	251/	E0\/	6 2) /	10\/	16\/	251/	E01/	6 31/	10\/	16\/	251/	E0\/	6 2)/	10\/	16\/	251/	E0\/	6 2)/	10\/	16\/	251/	EOV/
Voltage	0.31	100	100	250	500	0.30	100	100	250	500	0.31	100	100	250	500	0.30	100	100	250	500	0.31	100	100	250	500
330pF																									
470pF		4	610	2			4	610	2			4	610	2			1	610	2			4	610	2	
560pF		1	.6±0.	.ა			'	.6±0.	.3			'	.6±0.	3			'	.6±0.	.ა			1	.6±0.	3	
680pF		1.020.0																							



	FENGHUA				
1nF					
2.2nF					
3.9nF					
4.7nF					
5.6nF					
6.8nF					
10nF					
15nF					
18nF					
22nF					
33nF					
47nF					
56nF					
68nF					
100nF					
220nF					
330nF					
470nF					
680nF					
1µF					
2.2µF					
3.3µF	1.6±0.3	1.6±0.3	1.6±0.3	1.6±0.3	1.6±0.3
4.7µF					1.010.3
6.8µF					

Dimension												(4.5n	1812 nm*3	2 .2mm	1)										
Dielectric		X7	R 系	列			X	7S 系列	列			X7	/T 系	列			X6S	/X6T	系列			X5	R系	列	
Capacity/ Voltage	6.3 V	10V 1	6V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V	6.3V	10V	16V	25V	50V
330pF																									
470pF																									
560pF																									
680pF																									
1nF																									
2.2nF																									
3.9nF																									
4.7nF																									
5.6nF																									
6.8nF		1.6	0±0	.20			1.6	30±0.2	20			1.6	60±0.	20			1.0	60±0.	20			1.6	60±0	.20	
10nF																									
15nF																									
18nF																									
22nF																									
33nF																									
47nF																									
56nF																									
68nF																									
100nF																									

220nF

Dimension												(4.5r	1812		٠١										
Distriction			/7D 7	Ø ∓il				70 %	Til Til			•			1)		V00	WOT				\/r	-D 7	T II	
Dielectric			(7R ₹	ド グリ				7S 系 	ניע				7T 系 	رانخ 			705	701	系列			X	SR 系	. タリ 	
Capacity/	6.3	10\/	16\/	251/	50\/	6 31/	10\/	16\/	25\/	50\/	6 31/	10\/	16\/	25\/	50\/	6 31/	10\/	16\/	25\/	50\/	6.3V	10\/	16\/	25\/	50\/
Voltage	٧	100	100	250	300	0.5 V	100	100	250	300	0.31	100	100	25 V	30 V	0.3 V	100	100	250	30 V	0.31	100	100	25 V	300
330nF																									
470nF		4	.60±0	20			4 (60±0.	20			4 (30±0.	20			4 (30±0.	20			1 (30±0	20	
680nF		'	.0U±0	J.2U			1.0	0U±U.	20			1.0	ou±u.	20			1.1	ou±u.	.20			1.0	υ±υ	.20	
1µF																									
2.2µF																									
3.3µF		,	2.0±0	20			2	.0±0.2	20			2	0±0.2	20		2.0±	0.20					2	0±0.	20	
4.7µF		4	2.U I U	.20			2.	.U <u>T</u> U.2	20			2.	U±U.2	20		Z.UI	0.20					2.	U±0.	20	
6.8µF																									

Note: 1, [] General thickness corresponds to the capacity, unit: mm2, We can design according to the customer requirements

Reliability Test

Item	Т	echnical Specification		Test	Method and Remark	s
		Should be within the	С	apacitance	Measuring Frequency	Measuring Voltage
	ClassI	specified tolerance.		≤1000pF	1MHz±10%	4.0.0.0\/
				> 1000 pF	1KHz±10%	1.0±0.2Vrms
Capacitance	Class II	Should be within the specified tolerance.	C≤10µF Test Fre Test Vol C > 10µF Test Fre	quency: 1KHz±10 tage: 1.0±0.2Vrm	0% s ⊣z	
		C≤10 nF, Ri≥50000MΩ		Manager Val	D - (- 1) / - (/	M 500\/ \
	ClassI	C > 10 nF, Ri•C _R ≥5009	S	Duration: 60±5	age: Rated Voltage(-	Max 500V)
Insulation Resistance	Class II	C≤25 nF, Ri≥10000M9 C > 25 nF, Ri•C _R > 100		Test Humidity: Test Temperati Test Current: ≤	≤75% ure: 25°C±3°C	
		注:S=Ω·F				
Dissipation		DF	Ca	pacitance	Measuring Frequency	Measuring Voltage
Factor	Classi	≤1/ (400+20C)	С	< 30 pF	1MHz±10%	1.0±0.2Vrms
		≤0.1%		C≥30pF	110111211070	1.010.2 VIIII3



Item			Technic	al Specificat	tion				Test Me	ethod and R	emarks
		电压	DF(×10 ⁻⁴)	1005	()201	0402	0603	0805	1206 及上	. C≤10µF
			≤250		-		≤10nF	< 100nF		≤680nF	Test
			≤350		≤3	.3nF	≤47nF	<470nF	≤1uF	≤2.2uF	Frequency:
		50V	≤500		≤1	0nF	≤0.1µF				1KHz±10%
			≤750		-				≤2.2uF	≤4.7uF	Test Voltage:
			≤1000					≤2.2µF	≤10µF	≤10µF	1.0±0.2Vrms
			≤250				≤10nF	< 100nF		≤680nF	0 × 40 × E
			≤350	——F	≤3	.3nF	≤47nF	< 470nF	≤1uF		C > 10µF X7R、X5R、X7T
		25V	≤500		≤1	0nF	0.22µF				X6S
			≤750		> '	10nF			≤2.2µF	≤10µF	Test
			≤1000		≤1	00nF	≤2.2µF	≤10µF	≤22µF	≤22µF	Frequency: 120±
5			250		-		≤10nF	< 100nF		≤680nF	24Hz
Dissipation Factor	Class		≤350	≤1nF	≤3	.3nF	≤47nF	< 470nF	≤1uF		Test Voltage:
Factor	"	16V	≤500		≤1	5nF	≤220nF	_			0.5 ±0.1Vrms
			≤750	≤10nF	≤4	7nF		_	≤4.7µF	≤10µF	•
			≤1000		≤1	00nF	≤4.7µF	≤10µF	≤22µF	≤47µF	
			≤250		-		≤10nF	< 100nF		≤680nF	
			≤350	≤1nF	≤3	.3nF	≤47nF	< 470nF	≤1uF		
		10V	≤500		≤1:	5nF	≤220nF				
			≤750	≤10nF	≤1	00nF			≤2.2µF	≤10µF	
			≤1000		≤2	.2µF	≤10µF	≤22µF	≤47µF	≤100µF	
			≤250		-		≤10nF	< 100nF		≤680nF	
			≤350	≤1nF	≤3	.3nF	47nF	< 470nF	≤1uF		
		≤ 0.0\/	≤500		≤1	5nF	≤220nF				
		6.3V	≤750	≤10nF	≤4	7nF			≤2.2uF	≤10µF	
			≤1000		≤2	.2µF	≤10µF	≤47µF	≤47µF	≤100uF	
Dielectric Withstanding Voltage	No bre	akdown	or damage.			Classl Duration	uring Voltage :300% Rated on: 1~5s method exclu	d voltage Charge/ Dis	charge C		
						Prehe	ating condition	ons:80 to 120)°C; 10~3	30s.	
Solderability	covere	d by nev	of the termin w solder. ance: No visible		e is	Solder	soldering Temperatur on: 2±0.5s	re: 235±5°C	Sol	d-free solde der Tempera ation: 2±0.5	ature: 245±5°C



Item	:NGHU	Technical Specification			Test Method and Remarks	
	Item	Classi	Class II	Preheat	ing conditions: 100 to 200°C; 60-120) seconds.
	10/0	≤±2.5% or ±0.25PF , whichever	. 450/		emperature: 265±5°C	
Resistance to	ΔC/C	is larger	±15%	Duration		
Soldering	DF	Same to initial value.			ne capacitor with solvent and exam	ine it with a
Heat	IR	Same to initial value.		10X(mir	n.) microscope.	
	Appeara	nce : No visible damage.At least	95% of the	Recove	ry Time: 24±2h.	
	terminal	electrode is covered by new solder.		Recover	ry condition: Room temperature	
Resistance to Flexure of Substrate (Bending Strength)	ΔC/C:	nce: No visible damage. ≤±5%或±0.5pF,whichever is larger. ≤±10%		Speed:	ard: PCB Warp: 1mm 1mm/sec. Unit: mm asurement should be made with t	he board in
				the bend	45±2 45±2 ding position.	
Termination Adhesion	No visibl	e damage.			施加力T	and hold for 魔力工具 / PCB 哲
					ing conditions: up-category tempera	
	Item	ClassI Class ≤±1% or ±1pF ,	SII		ry time: 24±1h easurement	
	ΔC/C	whichever is larger	-1 15%		easurement Times: 5 times, 1 cycle, 4 steps:	
	No visibl	e damage.		Step	Temperature(°C)	Time
Temperature Cycle				1	Low- category temp: :-55	30min
				2	Normal temp : +20°C	2 ~ 3min
				3	Up- category temp (COG/X7R/X7T/X7S: +125 X5R:+85 X6S/X6T:+105)	30min
				4	Normal temp : +20°C	2 ~ 3min
				Recover	ry time after test:24±2h	



Item			Technic	al Specification			Т	est Method a	ind Remarks	
	ΔC		ssl: ±7.5% ssll: ≤±12.5	or ±0.75pF, whichever is larger.			140 ℃		Class II) : After pr 1h ± 10min, pla 2h.	_
	DF	Not	more than t	twice of initial value.				ity: 90~95%F e: Rated Volt		
I I			Classl	Ri≥5000MΩ或 Ri•C _R ≥50S which smaller.	hev	ver is	Recove	on: 500h ery Time: 24ł 2 : 0201≥47n	n±2h iF、0402≥33nF、	0603≥1µF、
Humidity load	IR		Class II	Ri≥1000MΩ或 Ri•C _R ≥10S which smaller.	hev	ver is	in 150°	C、1h after to de after beir	i≥10μF product no the test ,and meas ng kept at room t	surement to
	App	pearance:	No visible	damage.						
					T	፠ Pre	 etreatmen	t (ClassII) :	After preheating	at 140 °C
	Δ	ClassI	≤±3%或±	£0.3pF, whichever is larger.	Ш		for 1h±1	0min, place	at room temperat	ture for 24±
	C/ C	Class	-20% ~	+20%			ltage(<br Voltage: 2	100V) 2*Ur,except	the table 1	
	DF	Not mo	≤2 倍初始 re than twic	計标准 ce of initial value.	Ш		n: 1000h rature : 12	5°C (C0G、	X7R、X7S) 85	°C (X5R)
	IR	Classl	小者 Ri≥4000l	MΩ或 Ri•C _R ≥40S 取两者之中较 MΩ或 Ri•C _R ≥40S ver is smaller.		Charge/ Recove	ry Time: 2	e Current: 50 4h±2h)mA max. 33nF、0603≥1μF	、0805≥4.7
Life Test		Class		MΩ或 Ri•C _R ≥50S ver is smaller.				roduct need	to keep in 150°C、	1h after the
	Арре	earance: N	No visible d			table Capa	1 acitance	testing	Capacitance	testing voltage
						0201	1≥10nF	voltage	0805≥0.47uF	voitage
						_	2≥47nF	1.5Ur	1206≥1uF	1.5Ur
						0603	≥220nF		1210≥1uF	
								urement to be for 24±2h.	e made after be	eing kept at

Note:

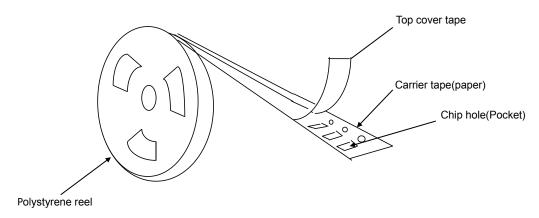
Pretreatment (only for class2 capacitor)

Pretreatment (only for class2 capacitor) is a method to treat the capacitor before measurement. First, place the capacitor in the up-category temperature or other specified higher temperature environment for 1hour. Then recovery the capacitor at standard pressure conditions for 24±1hours_o

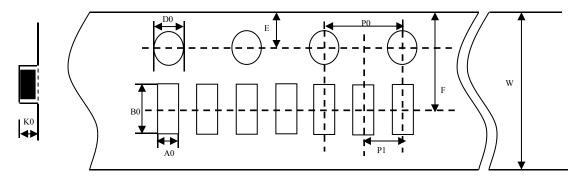


Package

* Embossed Plastic Taping

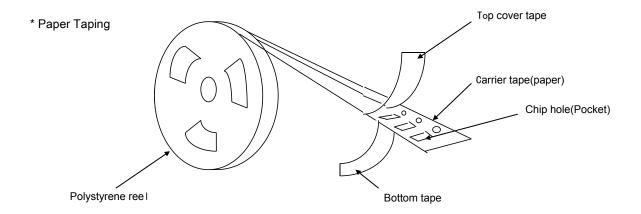


 * The emboss plastic applies only to 1005 $\,$ type , the dimensions as follows:



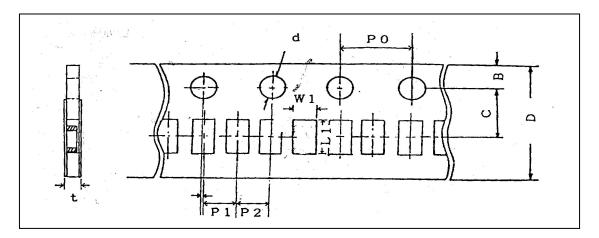
Unit: mm

W	P0	P1	E	F	D0	Α0	В0	K0
4±0.05	2±0.04	1±0.02	0.9±0.05	1.8±0.02	0.8±0.04	0.24±0.02	0.45±0.02	0.24±0.02



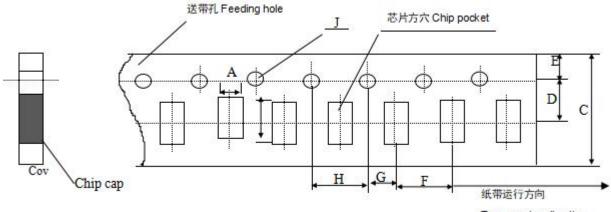


* Dimensions of paper taping for 1005、0201、0402 type



Code	W1	L1	D	С	В	P1	P2	P0	d	t
1005	0.24	0.45	8.00	3.50	1.75	2.00	2.00	4.00	1.50	0.30
1005	±0.02	±0.02	±0.10	±0.05	±0.10	±0.05	±0.05	±0.10	-0/+0.10	Below
0204	0.37	0.67	8.00	3.50	1.75	2.00	2.00	4.00	1.50	0.80
0201	±0.10	±0.10	±0.10	±0.05	±0.10	±0.05	± 0.05	±0.10	-0/+0.10	Below
0400	0.65	1.15	8.00	3.50	1.75	2.00	2.00	4.00	1.50	0.80
0402	±0.10	±0.10	±0.10	±0.05	±0.10	±0.05	±0.05	±0.10	-0/+0.10	Below

*Dimensions of paper taping for 0603 , 0805 , 1206 types.



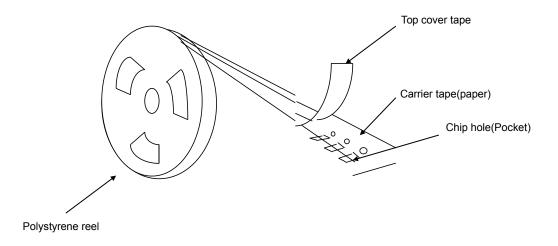
Tape running direction

Unit: mm

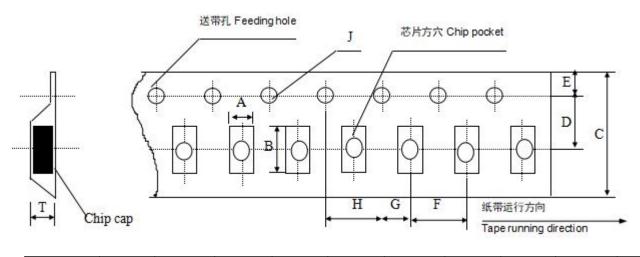
Code paper size	A	В	С	D*	E	F	G*	Н	J	Т
0603	1.10	1.90	8.00	3.50	1.75	4.00	2.00	4.00	1.50	1.10
0603	± 0.10	± 0.10	± 0.10	± 0.05	± 0.10	± 0.10	± 0.10	± 0.10	-0/+0.10	Max
0805	1.45	2.30	8.0	3.50	1.75	4.00	2.00	4.00	1.50	1.10
0605	± 0.15	± 0.15	± 0.15	± 0.05	± 0.10	± 0.10	± 0.10	± 0.10	-0/+0.10	Max
1206	1.80	3.40	8.00	3.50	1.75	4.00	2.00	4.00	1.50	1.10
1206	± 0.20	± 0.20	± 0.20	± 0.05	± 0.10	± 0.10	± 0.10	± 0.10	-0/+0.10	Max



* Embossed taping



* Dimensions of embossed taping for 0805~1812 type

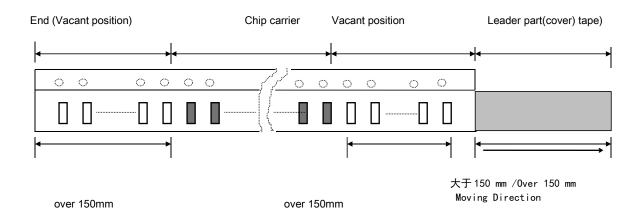


Code Tape size	А	В	С	D*	E	F	G*	Н	J	Т
0805	1.55	2.35	8.00	3.50	1.75	4.00	2.00	4.00	1.50	1.50
	± 0.20	± 0.20	± 0.20	± 0.05	± 0.10	± 0.10	± 0.10	± 0.10	-0/+0.10	Max
1206	1.95	3.60	8.00	3.50	1.75	4.00	2.00	4.00	1.50	1.85
	± 0.20	± 0.20	± 0.20	± 0.05	± 0.10	± 0.10	± 0.10	± 0.1	-0/+0.10	Max
1210	2.70	3.42	8.00	3.50	1.75	4.00	2.00	4.00	1.55	3.2
	± 0.10	± 0.10	± 0.10	± 0.05	± 0.10	± 0.10	± 0.05	± 0.10	-0/+0.10	Max
1808	2.20	4.95	12.00	5.50	1.75	4.00	2.00	4.00	1.50	3.0
	± 0.10	± 0.10	± 0.10	± 0.05	± 0.10	± 0.10	± 0.05	± 0.10	-0/+0.10	Max
1812	3.66	4.95	12.00	5.50	1.75	8.00	2.00	4.00	1.55	4.0
	± 0.10	± 0.10	± 0.10	± 0.05	± 0.10	± 0.10	± 0.05	± 0.10	-0/+0.10	Max

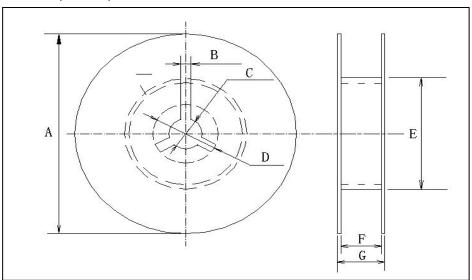
Note : The place with "*" means where needs exactly dimensions.



* Structure of leader part and end part of the carrier paper

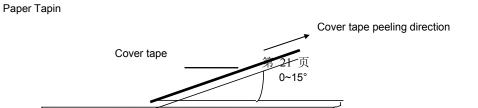


* Reel dimensions (unit: mm)



Reel model	А	В	С	D	E	F	G
7'REEL	φ178±2.0	3.0	φ13±0.5	φ21±0.8	φ50 或更大 φ50 or more	10.0±1.5	12max

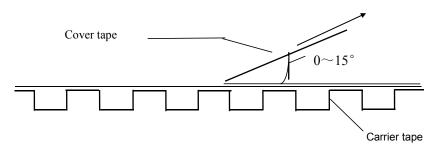
* Taping specification : top tape peeling strength





*Embossed Taping

Cover tape peeling direction



Standard: 0.1N < peeling strength < 0.7N

No paper dirty remains on the scotch when peeling, and sticks to top and bottom tape.

* Bulk Case Package

单位(unit):mm

Symbol	А	В	T	С	D	E
Dimension	6.80±0.10	8.80±1.00	12.00±0.10	15.00+0.10/-0	2.00+0/-0.10	4.70±0.10
Symbol	F	W	G	Н	L	I
Dimension	31.50+0.20/-0	36.00+0/-0.20	19.00±0.35	7.00±0.35	110.00±0.70	5.00±0.35

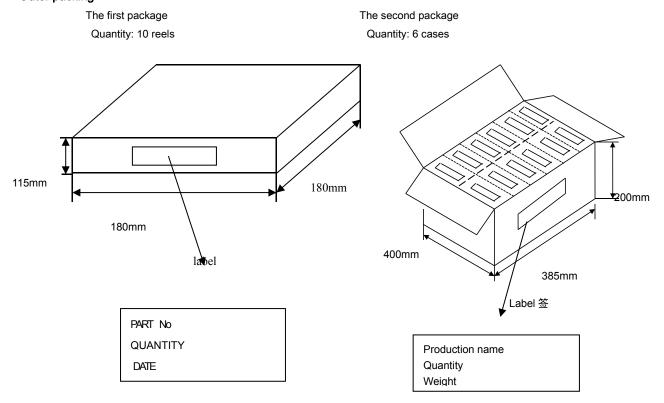
* Packing Quantity

		Package Style & Quantity unit: pcs					
(SIZE)	EPT	PT	ET	ВС	BP		
1005		20000					
0201		15000					
0402		10000		20000	5000		
0603		4000		15000	5000		
0805		4000	3000	10000	5000		
1206		4000	T≤1.35mm 3000 T > 1.35mm 2000	5000	5000		
1210			T≤1.80mm 2000 T > 1.80mm 1000		2000		
1808			2000		2000		
1812			T≤1.85mm 1000 T > 1.85mm 500		2000		

Note: We can choose packing style and quantity can be according to the customer's requirement.



* Outer packing



Storage Methods

- * The guaranteed period for solderability is 12 months (Under deliver package condition).
- * Storage conditions:

Temperature 5~40°C Relative Humidity 20~70%

Precautions For Use

The Multi-layer Ceramic Capacitors (MLCC) may fail in a short circuit modern in an open circuit mode when subjected to severe conditions of electrical environment and / or mechanical stress beyond the specified "rating" and specified "conditions" in the specification, which will result in burn out, flaming or glowing in the worst case. Following "precautions for "safety" and Application Notes shall be taken in your major consideration. If you have a question about the precautions for handling, please contact our engineering section or factory.

* Soldering Profile

To avoid the crack problem by sudden temperature change, follow the temperature profile in the adjacent graph (refer to the graph in the enclosure page).

* Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in capacitors. The hot soldering iron tip comes into direct contact with the end terminations, and operator's careless may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor. Therefore the soldering iron must be handled carefully, and pay much attention to the selection of the soldering iron tip and temperature contact of the tip.

*Optimum Solder Amount for Reflow Soldering

Too much solder

Cracks tend to occur due to large stress.



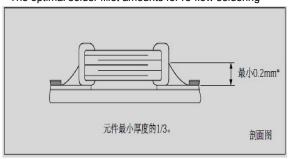
Not enough solder



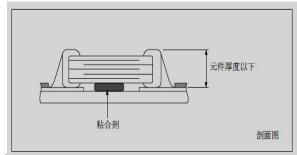
Weakholding force may cause badconnection between the capacitor and PCB.

* Recommended Soldering amounts

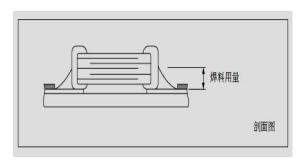
The optimal solder fillet amounts for re-flow soldering



The optimal solder fillet amounts for wave soldering



The optimal solder fillet amounts for reworking by using soldering iron



* Recommended Soldering Method

Size	Temperature Characteristics	RatedVoltage	Capacitance	Soldering Method
1005	COG	1	1	R
1005	X7R/X5R/X7T/X6S	1	1	R
0204	COG	1	1	R
0201	X7R/X5R/X7T/X6S	1	1	R



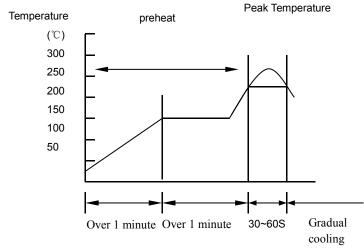
*Recommended Soldering Method

Size	Temperature Characteristics	RatedVoltage	Capacitance	Soldering Method
0400	COG	1	/	R
0402	X7R/X5R/X7T/X6S	1	/	R
	COG	1	/	R/W
0603	0603 X7R/X5R/X7T/X6S	1	C≥1uf	R
		/	C < 1uf	R/W
	COG	1	/	R/W
0805	VZD/VCD/VZT/VCC	1	C≥4.7uf	R
	X7R/X5R/X7T/X6S	/	C < 4.7uf	R/W
	COG	1	/	R/W
1206	1206 X7R/X5R/X7T/X6S	,	C≥10uf	R
		1	C < 10uf	R/W
>4040	COG	1	/	R
≥1210	X7R/X5R/X7T/X6S	1	/	R

Soldering method : Reflow Solering Wave Soldering

• The temperature profile for soldering

* Re-flow soldering

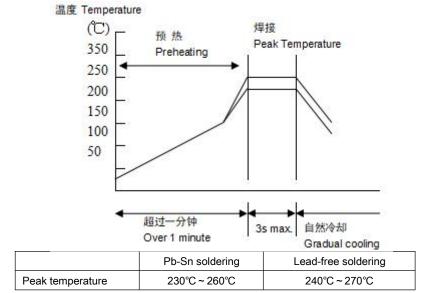


	Pb-Sn soldering	Lead-free soldering
Peak temperature	230℃~250℃	240℃~260℃

While in preheating, please keep the temperature difference between soldering temperature and surface temperature of chips as: $T \le 150 \, ^{\circ}$ C.

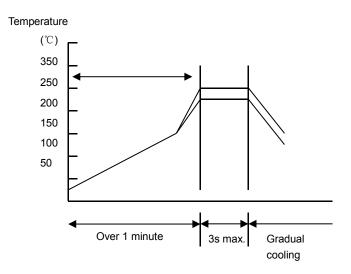


* Wave soldering



While in preheating, please keep the temperature difference between soldering temperature and surface temperature of chips as: $T \le 150$ °C.

* Hand soldering



Conditions :

Preheating	Temperature of soldering iron head	Power of soldering iron	Diameter of soldering iron head	Soldering time	Solder paste amount	Restricted conditions
△≤130°C	Highest temperature:35 0°C	20W at the highest	1mm recommended	3s at the longest	≤1/2 chip thickness	Please avoid the derect contact between soldering iron head and ceramic components

^{*}The latest version of the content shall prevail

Features

- Miniature size
- Wide capacitance, TC, voltage and tolerance range
- Industry standard sizes
- Available for wave, reflow or vapor phase solder

How to Order

0805	В	104	K	500	N	T
↑	1	1	1	1	↑	
Α	В	С	D	E	F	G

Α

Size Code Inche

0402

0603

0805 1206

1210

1812

2225

ode Inches	- 1
0.04×0.02	В
0.06×0.03	
0.08×0.05	Х
0.12×0.06	
0.12×0.10	
0.18×0.12	
0.22×0.25	

Dielectric				
В	X7R			
Х	X5R			
_ ^	XJIX			

В

	Normal Capacitance
102	10×10 ²
103	10×10 ³

С

Express by three figures. Unit used is pF (pico-farad)

First two figures are significant digit, third figure expresses number of zeros which follow the two significant digit

If there is a decimal place it is represented by a "R". In this scenario all figures are significant digit

D

0.30×0.35

Tolerance				
K	±10%			
М	±20%			

|--|

Rated Voltage					
160	16×10 ⁰				
250	25×10 ⁰				
500	50×10 ⁰				
630	63×10 ⁰				
101	10×10 ¹				
201	20×10 ¹				
501	50×10 ¹				
102	10×10 ²				
202	20×10 ²				

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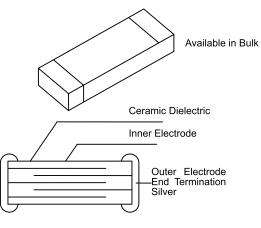
<u> </u>				
Termination				
S	Silver			
N	Nickel Barrier			
IN .	Tin plating			

G

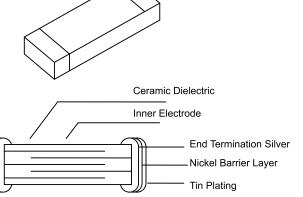
Packaging Style				
Т	Tape & Reel			
В	Bulk Package			

Termination Diagrams





Barrier Layer



NOTE: Other Termination Available Upon Request (Contact Factory)

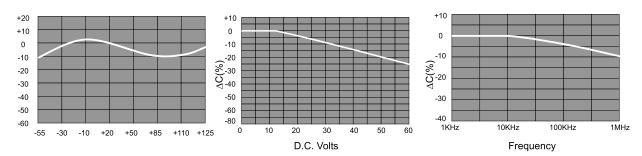
X7R - Dielectric Characteristic Introduction & Test Method (Table 1)

Item	Spe	cification	Test Method	
Capacitance	(100F	PF∼2.2uF)		
	K	=±10%		
Capacitance Tolerance	М	=±20%		
'	S=±5	50%/-20%		
Date d Valta va	16、25、50、	63、100、200、	1KHz±10%,1.0±0.2Vrms	
Rated Voltage	500、100	00、2000VDC		
	1000、	2000VDC		
Dissipation Factor DF:<0.25%(100V)				
(DF)	<3.0%(50V、25V)		
	<3.	5%(16V)		
			Test Voltage: rating voltage	
Insulation Resistance	C≤25nF	:R>4000ΜΩ	Charging time:1min	
(IR) C>25nF:RxC>100S			Temperture:18∼25°C	
			Humidity:<80°C	
Dielectric	There shall be no	evidence of damage	Apply 2.5 x rating voltages to both Terminations	
Withstanding Voltage	or flash		for 5 seconds. Charge and discharge current	
withstanding voltage	over during the test.		are less than 50mA.	
Termination Adhesion	There shall be no evidence of damage		Test Condition:5N:10±1s	
Termination Adiresion	during the test.		Test Condition. 11. 102 15	
	There shall be no	evidence of damage	After soldering capacitor on the PCB, 1mm of	
Bending Strength	during the test; capa	citance tolerance shall be	bending shall be applied for 1 second as show	
	not mor	e than 10%.	by Drawing.	
	Termination area shall be	e at least 80% covered with a		
Solderabillity	new solder coating. There shall be no crack and ceramic			
	exposure of terminated surface by melting.		The capacitors are completely immersed during	
	Туре	X7R(B)	2 in the molten rosin, Then immersed 10mm	
	Temp	265±5°C	during 2±1s in the molten solder with a temperature of 235±5°C.Pick up the	
Resistance to Soldering Heat	Time	5±1s	capacitors-and cleaned with solvent, and put in	
Coldering fleat	Cover%	≥85%	on the> 10 times microscope.	
	∆C/C	-5~+10%		

X7R - Dielectric Characteristic Introduction & Test Method (Table 2)

Item	Spe	cification	Test Method		
	Туре	X7R	Condition	X7R	
	∧c/c	≤1%	Temp.Oa	-55±3°C	
Temperature	△0/0	≥170	Temp.Ob	+125±3°C	
Cycling	Thoro shall be n	o evidence of damage	Cycle times	5 times 30min/time	
		ng the test.	Resume time	24h	
	duiii	ig the test.	Changing times	$2{\sim}3$ min	
	Туре	X7R		Permanent moisture:	
Humidity &	△C/C	≤10%		T=40±2°C	
Moisture	DF	0.05		t=21d	
Resistance	IR	RxC>25s	Relative humidity: 93+2%-3%		
Resistance	There shall be n	o evidence of damage	•	Resume time: 1~2h	
	durii	ng the test.		recourse time.	
T.C.	Dielectric	∆C/C	Dielectric	T.C	
Characteristics	X7R	±15°C	X7R +20°C→-55°C→+20°C→+125°		
Vibration	There shall be no evidence of damage during the test.		Vik	oration frequency: f=10∼500HZ	
				Vibration range:0.75mm/s2	
		<u>-</u>		in 3 direction:2h/direction	
	Туре	X7R	4000		
Bump	△C/C	≤2%	addeleration :390m/s2		
	There shall be no evidence of damage		Pulse duration:6ms		
		ng the test.			
	Type	X7R	Condition	X7R	
	△C/C	≤2%	Temp	+125°C	
Life test	DF	0.003	Time	T=100th	
	IR	RxC>25s	Voltage	V=1.5Vr	
		o evidence of damage	Resume time	24±1h	
		ng the test.	O a sa diti a sa	VZD	
	Type △C/C	X7R ≤10%	Condition	X7R 60%	
	DF	0.05	Creditability	+125°C	
6 grade failure test			Temp		
	IR	RxC>25s	Voltage	Rating Voltage	
		o evidence of damage ng the test.	Time	1000h	
	durii	ig the test.			

Typical Characteristic



Size Code Capacitance And Voltage(Table 1)

		Dimensi	- Voltage -	Capacitance (pF)		
Size Code	٦	W	Т	Me	voitage	X7R
					10V	101~105
0402	1.0±0.05	0.5±0.05	0.5±0.05	0.1±0.05	16V	101~223
0402	1.0±0.05	0.5±0.05	0.5±0.05	0.1±0.05	25V	101~103
					50V	101~392
					25V	101~333
0603	1.6±0.1	0.8±0.10	0.8±0.1	0.3±0.1	50V	101~223
0603	1.0±0.1	0.0±0.10	U.O±U.1	0.3±0.1	100V	101~472
					200V	
			$0.7\pm^{0.3}_{0.2}$		25V	331~104
					50V	331~473
0805	2.00±0.20	1.25±0.20	1.25±0.15	0.5±0.25	100V	331~223
					200V	222~153
			1.0±0.3		500V	222~123
					25V	102~224
					50V	102~104
			1.0±0.3		100V	102∼683
1206	3.20±0.30	1.60±0.20		0.5±0.25	200V	221~223
			1.25±0.2		500V	221~223
					1000V	221~472
					2000V	680~102
					25V	102~334
					50V	102~224
			1.0±0.3		100V	102~104
1210	3.20±0.30	2.50±0.30		0.70±0.25	200V	102~683
			1.25±0.3		500V	222~473
					1000V	102~153
					2000V	181~152
					25V	103~474
					50V	103~334
					100V	103~224
1812	4.50±0.40	3.20±0.30	2.5	1.00±0.25	200V	682~104
					500V	472~124
					1000V	222~273
					2000V	331∼332

Size Code Capacitance and Voltage (Table 2)

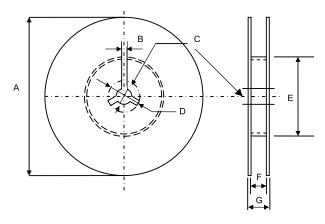
		Dimens	Voltage	Capacitance (pF)		
Size Code	L	W	Т	T Me		X7R
			25V	103~105		
					50V	103~105
					100V	103~474
2225	5.70±0.50	6.40±0.50	2.5	1.00±0.25	200V	153~424
					500V	183~394
					1000V	822~104
					2000V	122~103
					25V	103~225
					50V	103~225
						100V
3035	7.60±10.50 9.00±0.50	3.0	1.00±0.25	200V	103~125	
					500V	682~105
					1000V	
					2000V	

Packaging

Structure and Dimension

Tape & Reel

Α	B*	С	D*	E	F	G
178±2.0	3.0	13±0.5	φ32	50MIN	10.0±	14.9
				φ±1	1.5	12±2.0

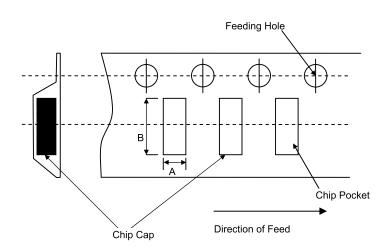


Paper Tape

Size	A	В
0402	0.6±0.2	1.1±0.2
0603	1.1±0.2	1.4±0.2
0805	1.45±0.2	2.3±0.2
1206	1.8±0.2	3.4±0.2

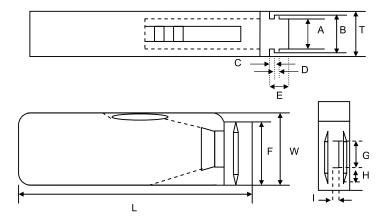
Plastic Tape (Te)

Size	A	В
0402	0.5±0.2	1.2±0.2
0603	0.8±0.2	2.0±0.2
0805	1.65±0.2	2.4±0.2
1206	2.0±0.2	3.6±0.2



Cartridge

Symbol	Α	В	D	С	T	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	15±0.1-0	2±0-0.1	4.7±0.1
Symbol	F	W	G	Н	L	1
Dimension	31.5±0.2-0	36±0-0.2	19±0.35	7±0.35	110±0.7	5±0.35



Packaging Quantity

Size	Quantity				
	Paper Tape Taping	Plastic Embossed Tapping	Bulk Packaging		
0402	10000		10000		
0603	4000		4000		
0805	4000	2000 / 3000	4000		
1206	4000	2000 / 3000	4000		
1210		2000 / 3000	2000		
1808		2000 / 3000	2000		
1812		1000	2000		
2225					
3035					

Fenghua MLCC Product Classification

Fenghua Automotive MLCC--AM Series

There is high reliability on monolithic structure of laminated layers.

And its character of excellent soldering ability and soldering resistance ability is suitable for reflow soldering and peak soldering. It includes high and stable capacitance.

This type of capacitor is a special electronic component for automobiles, which has passed all the experimental conditions set by the AEC-Q200 standard, and is more stable and safe during automobile use. The materials used mainly include C0G with high temperature stability and X7R, X5R, X7S, and X7T with high dielectric constant



Automotive MLCC--AE Series



Automotive MLCC--AS Series



EMI Fliters MLCC

EMI has excellent performance in high current applications, non-polar and suitable for high-density surface mounting, superior filtering characteristics. It can absorb noise and restrain surge pulse, offering food solder-ability and leach-ability.



Arrays MLCC

C-array series MLCC can save 50% space of the PCB and improve the assembly density; the installation of a CA is equal to the installation of 4 pieces of 0603 capacitors, reducing the times of installation and improving installation efficiency; reduce the times of placement, easy to install and shorten production time, reduce equipment management costs and PCB costs; Improve the working efficiency of the printed board: Reduce the amount of printed circuits and promote the working speed of the printed circuit.



High Voltage Series

High voltage MLCC is a kind of special design MLCC that bases on the technology of general MLCC. This kind of MLCC has stable high voltage reliability and suitable to SMT. It is widely applicable for many direct high voltage circuits which can improve the performance of the circuit.



Safety MLCC Safety MLCC-X1,Y2



Flexible Series

MLCC with flexiterm has high strength resistance to bending for 3mm, increasing the times of temperature cycle change, up to 3000 times. Flexible terminal system can reduce the failure of circuit board caused by bending. Applications for high - bending circuit boards, temperature - varying circuits and automotive propulsion systems.



Microwave MLCC

Microwave MLCC (RF series) is characterized by high Q value, low equivalent series resistance and high self resonant frequency. Applicable to mobile communication base stations, wireless communication products, RF power amplifiers, impedance matching networks, filtering networks and VCO.



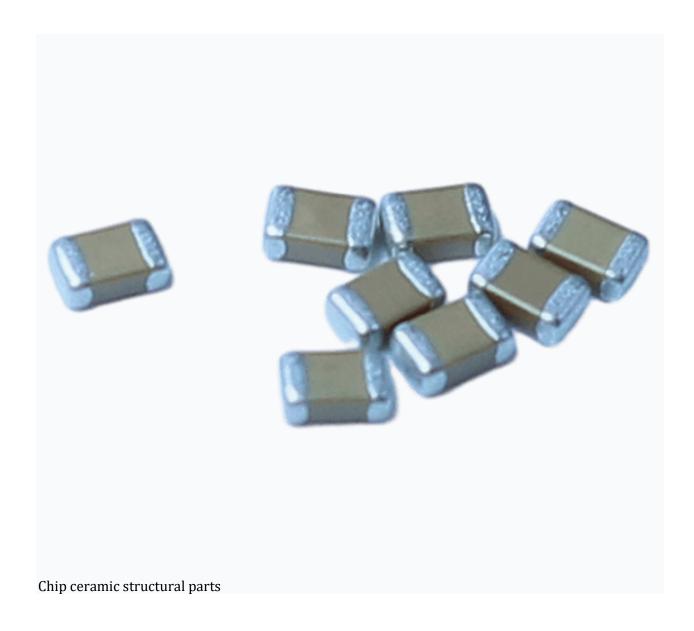
High Q MLCC

High Q MLCC (HQ series), characterized by high Q and low equivalent series resistance, are used in communication equipment, RF power amplifiers and filtering networks.



Open-Mode MLCC

 \mbox{MLCC} with open mode design is characterized by protecting the circuit when MLCC cracks.





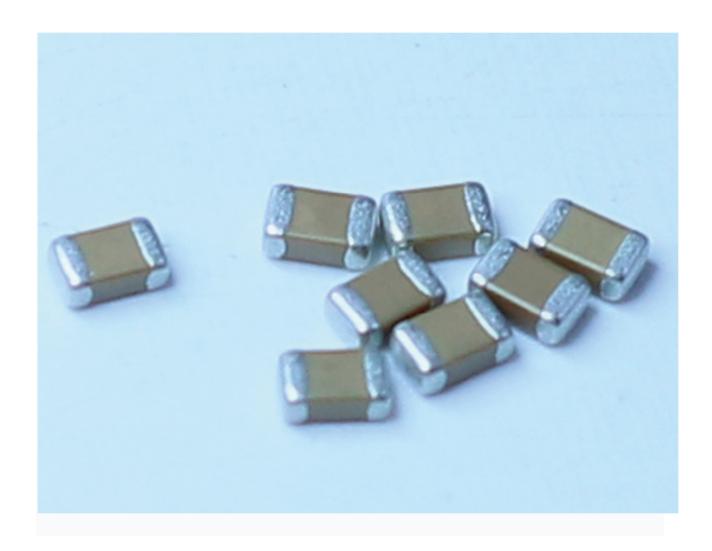
Industial Grade Series

Industrial MLCC is specially designed for industrial electronic automation equipment, network core equipment and related electronic products; It has high reliability, suitable for harsh application conditions, high quality requirements, low failure rate of all kinds of electronic products.



General MLCC

- **HIGH FREQUENCY TYPE: The capacitor of this kind dielectric material is considered as ClassIcapacitor, including high frequency COG、COH capacitor and temperature compensating capacitor such as HG, LG, PH, RH,SH, TH, UJ, SL. The electrical properties of COG、COH capacitor are the most stable one and change invariablly with temperature, voltage and time. They are suited for applications where low-losses and high-stability are required, HG, LG, PH, RH, SH, TH, UJ, SL capacitor's capacitance changes with temperature. They are suited for applications where low-losses and temperature compensating circuits.
- **X7R、X5R、X7S、X6S: X7R、X5R、X7S、X6S material is a kind of material has high dielectric constant. The capacitor made of this kind material is considered as Class II capacitor whose capacitance is higher than that of class I. These capacitors are classified as having a semi-stable temperature characteristic and used over a wide temperature range, such in these kinds of circuits, DC-blocking, decoupling, bypassing, frequency discriminating etc.
- *Y5V: The capacitor made of this kind of material is the highest dielectric constant of all ceramic capacitors. They are used over a moderate temperature range in application where high capacitance is required because of its unstable temperature coefficient, but where moderate losses and capacitance changes can be tolerated. Its capacitance and dissipation factors are sensible to measuring conditions, such as temperature and voltage, etc.
- XZ5U: The capacitor made of this kind of material is considered as ClassII capacitor, whose temperature characteristic is between that of X7R and Y5V. The capacitance of this kind of capacitor is unstable and sensible to temperature and voltage. Ideally suited for bypassing and decoupling application circuits operating with low DC bias in the environment approaches to room temperature.



MLCC Application

LCD TELEVISION WASHING MACHINE